

10/789,638

3-21-05

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IFCw



ED626382590US

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

In re PATENT APPLICATION:

Application No.: 10/789,638

Attorney Docket: Solx 4

Filing Date: February 27, 2004

Examiner: Nadine G. Norton

First Inventor: David L. Bender

Art Unit: 1765

For: SYSTEM FOR CONTINUOUS  
GROWING OF MONOCRYSTALLINE  
SILICON

**PRELIMINARY AMENDMENT**

Honorable Commissioner for Patents and Trademarks  
P.O. Box 1450  
Alexandria, VA 22313-1450

Date: March 18, 2005

Sir:

Please preliminarily amend the subject application as follows. Each section of this amendment document begins on a separate sheet in accordance with 37 CFR 1.121.

03/22/2005 BABRAHA1 00000141 10789638

01 FC:2201 400.00 OP  
02 FC:2203 180.00 OP

Repln. Ref: 03/22/2005 BABRAHA1 0023171300  
DAH:501866 Name/Number:10789638  
FC: 9204 \$180.00 CR